TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS018C – Revised September 2003

CMOS Dual Complementary Pair Plus Inverter

High-Voltage Types (20-Volt Rating)

■ CD4007UB types are comprised of three n-channel and three p-channel enhancement-type MOS transistors. The transistor elements are accessible through the package terminals to provide a convenient means for constructing the various typical circuits as shown in Fig. 2.

More complex functions are possible using multiple packages. Numbers shown in parentheses indicate terminals that are connected together to form the various configurations listed.

The CD4007UB types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

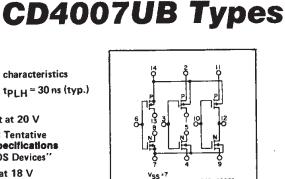
Medium Speed Operation — tpHL, tpLH = 30 ns (typ.)

Features:

- at 10 V = 100% tested for quiescent current at 20 V
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Standardized symmetrical output characteristics

Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C



vss 92cs- 25035 VDD×14 Terminal No.14 -- VDD

Terminal No. 7 – V_{SS}

FUNCTIONAL DIAGRAM

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LI	UNITS	
	MIN.	MAX.	
Supply-Voltage Range (For T _A = Full Package			
Temperature Range)	3	18	V

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
ISTIC	Vo (V)	VIN (V)							Max.		
Quiescent Dévice		0,5	5	0.25	0.25	7.5	7.5	_	0.01	0.25	
Current,		0,10	10	0.5	0.5	15	15	_	0.01	0.5	
IDD Max.		0,15	15	1	1	30	30	-	0.01	1	μΑ
		0,20	20	5	5	150	150		0.02	5	
Output Low	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_	
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8		
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1		mA
(Source)	2.5	0,5	5	-2	1.8	-1.3	-1.15	-1.6	-3.2	-	
Current, IOH Min.	9,5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	-	
Output Voltage:	_	0,5	-5	0.05				-	0	0.05	
Low-Level,	_	.0;10	10	0.05				-	0	0.05	
VOL Max.	_	0,15	15	0.05				-	0	0.05	
Output Voltage:	_	0,5	5	4.95			4.95	5			
High-Level,	-	0,10	10	9.95				9.95	10	-] [
VOH Min.	-	0,15	15		14	1.95		14.95	15	-	
Input Low	4.5	-	5			1		-	-	1	
Voltage, VIL Max.	9	-	10			2		-	—	2	
	13.5	-	15			2.5		-	_	2.5	v
Inpút High Voltage,	0.5	-	5	4				4			ľ
	1	-	10	8				8			4
VIH Min.	1.5	-	15	12.5				12.5	-	-	I
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10 ⁻⁵	±0.1	μA

Applications:

- Extremely high-input impedance amplifiers
- Shapers
- Inverters
- Threshold detector
- Linear amplifiers
- Crystal oscillators

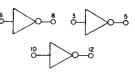
TERMINAL DIAGRAM Top View 02 (P) DRAM 10 Vbb, 016 02 8 03 (P) 02 (P) SURCE 2 13 SUBSTRATES, 01 (P)DRAM 02 (P) SURCE 2 13 01 (P) SURCE 02 (M) SOURCE 4 11 03 (P) DRAM 02 (M) DRAM 5 10 03 (P) DRAM 02 (M) DRAM 5 10 03 (P) DRAM 03 (M) DRAM 5 10 03 (M) DRAM 03 (M) DRAM 5 10 03 (M) DRAM 04 (M ZES 9 95 (M) SOURCE 9 05 (M) SOURCE 7 9 (D) (M) DRAM

9203-24449

CD4007UB Types

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE RANGE, (VDD)
Voltages referenced to V _{SS} Terminal)
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT
POWER DISSIPATION PER PACKAGE (PD):
For T _A = -55°C to +100°C
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (TA)
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max

a) Triple Inverters



9205-15350

(14,2,11); (8,13); (1,5); (7,4,9)

b) 3 -Input NOR Gate

(13,2); (1,11);

9205-15349

-012

(12,5,8); (7,4,9)

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}$ C; Input t_r , $t_f = 20 \text{ ns}$, C_L = 50 pF, R_L = 200 K Ω

	COND	ITIONS	LIN	1		
CHARACTER		V _{DD} Volts	Тур.	Max.	UNITS	
Propagation Delay T		5	55	110		
	TPHL.		10	30	60	ns
	IPLH		15	25	50	1
Transition Time	tTHL,	1	5	100	200	
			10	50	100	ns
	τιμ		15	40	80	1
Input Capacitance	CIN	Any Input		10	15	pF

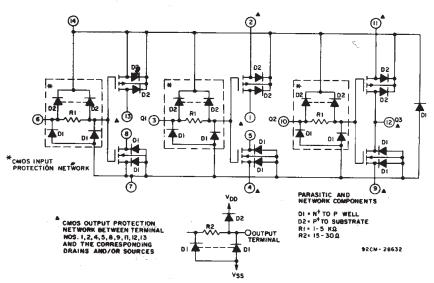
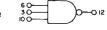


Fig. 1 - Detailed schematic diagram of CD4007UB showing input, output, and parasitic diodes.

c) 3-Input NAND Gate



(1,12,13); (2,14,11); (4,8); (5,9)

d) Tree (Relay) Logic

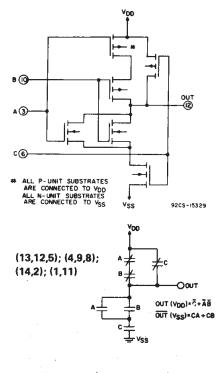


Fig. 2 - Sample CMOS logic circuit arrangements using type CD4007UB.

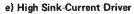
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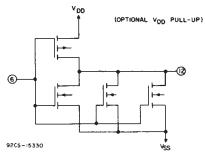
(6,3,10); (8.5, 12);

(11,14); 7,4,9)

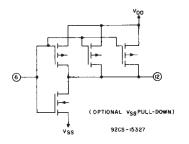
(6,3,10); (13,1,12);

(14,2,11); (7,9)

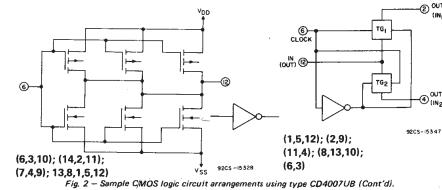


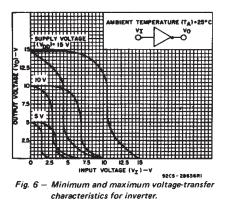


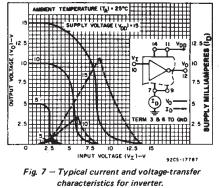
f) High Source-Current Driver



g) High Sink - and Source-Current Driver







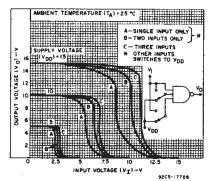
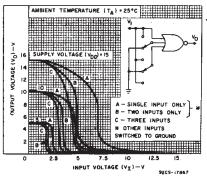
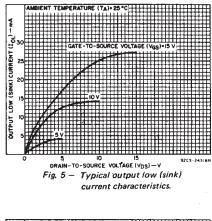
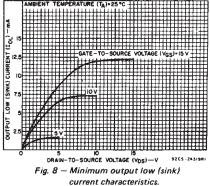


Fig. 3 - Typical voltage-transfer characteristics for NAND gate.



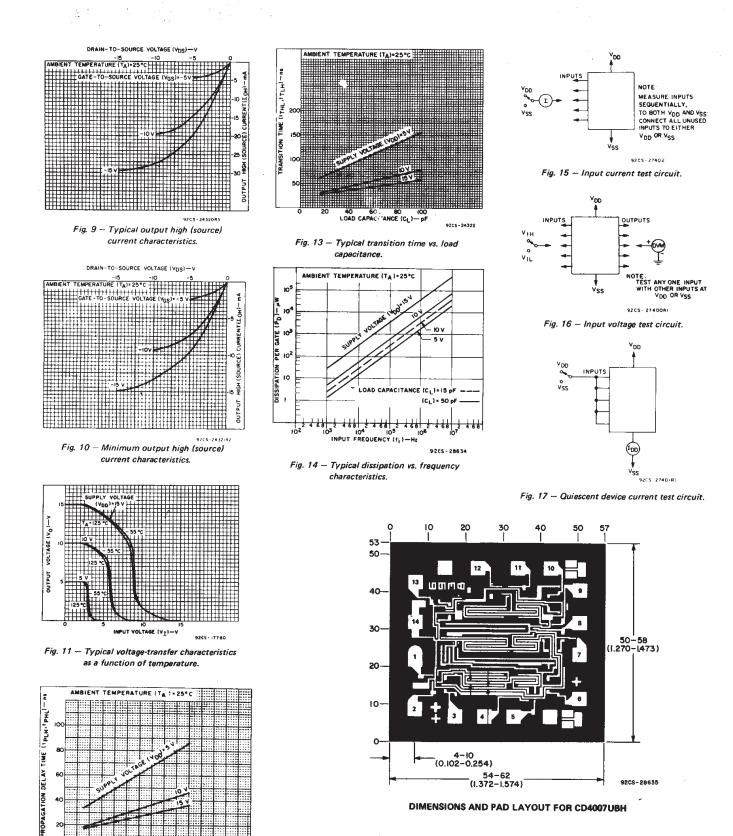
Typical voltage-transfer characteristics Fig. 4 for NOR gate.





h) Dual Bi-Directional Transmission Gating

-© ^{OUT}! (IN_I)



3

COMMERCIAL CMOS HIGH VOLTAGE ICs

92CS-28635

DIMENSIONS AND PAD LAYOUT FOR CD4007UBH

3-17

LOAD CAPACITANCE (CL) - pF 92CS-24434RI

Fig. 12 - Typical propagation delay time vs. load capacitance.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mile (10^{-3} inch) .

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4007UBE	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4007UBF	ACTIVE	CDIP	J	14	1	TBD	Call TI	N / A for Pkg Type
CD4007UBF3A	ACTIVE	CDIP	J	14	1	TBD	Call TI	N / A for Pkg Type
CD4007UBF3A116	OBSOLETE	CDIP	J	14		TBD	Call TI	Call TI
CD4007UBM	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBM96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBM96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBMT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBMTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBNSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBNSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBPWE4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4007UBPWRE4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD**: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AB.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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